

# Zertifikat *Certificate*

**Zertifikatsnummer Certificate No.:**

PV 50631004 0003

**Berichtsnummer Report No.:**

CN24PF66 003

**Genehmigungsinhaber License Holder:**

Sany Silicon Energy (Zhuzhou)  
Co., Ltd.  
No.333 Qingxia Road,  
Tongtangwan Street, Shifeng District,  
Zhuzhou City,  
412005 Hunan  
P.R. China

**Fertigungsstätte Manufacturing Site:**

Sany Silicon Energy (Zhuzhou)  
Co., Ltd.  
No.333 Qingxia Road,  
Tongtangwan Street, Shifeng District,  
Zhuzhou City,  
412005 Hunan  
P.R. China

**Prüfzeichen Test Mark:**

**Geprüft nach Tested according to:**

IEC 61215-1:2021  
IEC 61215-1-1:2021  
IEC 61215-2:2021  
IEC 61730-1:2023  
IEC 61730-2:2023  
EN IEC 61215-1:2021  
EN IEC 61215-1-1:2021  
EN IEC 61215-2:2021  
EN IEC 61730-1:2018  
EN IEC 61730-2:2018

**Geräteidentifikation**
*Product Identification*
**Produkt:**

PV Module

*Product:*
**Modell:**

Modelle sind auf nächste(r) Seite(n) gelistet

*Type:*
*Type designation(s) are listed on the next page(s)*
**Technische Daten:**

Class II acc. to IEC 61140

*Technical Data:*

For other ratings, refer to the test report.

**Gültig bis:**

2029-05-14

*Date of expiry:*
**Gültig ab:**

2024-08-21

*Valid from:*
**Zertifizierungsstelle:**
*Certification body:*

Angela Yao



Dem Zertifikat liegt unsere Prüf- und Zertifizierungsordnung zugrunde.  
Das Produkt entspricht den o.g. Anforderungen, die Herstellung wird überwacht.  
*This certificate is based on our Testing and Certification Regulation. The product fulfills above mentioned requirements, the production is subject to surveillance.*

**TÜV Rheinland LGA Products GmbH, Tillystraße 2, 90431 Nürnberg**
<http://www.tuv.com/safety> E-mail: markcheck@tuv.com

Fax: +49 221 806-3935

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**Berichtsnummer** *Report No.:*

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**Produkt** *Product:* PV Module

**Modell** *Type:*

**Bezeichnung** *Designation:*

Same as Page 0001-0002

In addition:

Max. System Voltage: up to 1500 VDC (Voc at STC):

With cut of mono c-Si cells: (Under STC)

SYMNI08TBDFBxxx (xxx=415-445, in steps of 5, 108 cells)

SYMNI156TBD0xxx (xxx=615-645, in steps of 5, 156 cells)

SYMNI156TBDLxxx (xxx=615-645, in steps of 5, 156 cells)

With cut of mono c-Si cells: (Under BNPI)

SYMNI08TBDFBxxx (xxx=457-490, 108 cells)

SYMNI156TBD0xxx (xxx=677-710, 156 cells)

SYMNI156TBDLxxx (xxx=677-710, 156 cells)

Power range extension for following models:

With cut of mono c-Si cells: (Under STC)

SYMNI156TBDxxx (xxx=640, 645, 156 cells)

SYMNI144TBDxxx (xxx=590, 595, 144 cells)

SYMNI120TBDxxx (xxx=490, 495, 120 cells)

SYMNI08TBDxxx (xxx=445, 108 cells)

SYMNI08TBDBxxx (xxx=445, 108 cells)

With cut of mono c-Si cells: (Under BNPI)

SYMNI156TBDxxx (xxx=704, 710, 156 cells)

SYMNI144TBDxxx (xxx=649, 655, 144 cells)

SYMNI120TBDxxx (xxx=539, 545, 120 cells)

SYMNI08TBDxxx (xxx=490, 108 cells)

SYMNI08TBDBxxx (xxx=490, 108 cells)

xxx represents output power in Wp

Remarks:

Update standard see above.

